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VS-SD400N/R Series

Vishay Semiconductors

Standard Recovery Diodes (Stud Version), 400 A



PRODUCT SUMMARY				
I _{F(AV)}	400 A			
Package	DO-205AB (DO-9)			
Circuit configuration Single diode				

FEATURES

- Wide current range
- High voltage ratings up to 2400 V
- High surge current capabilities
- Stud cathode and stud anode version
- Standard JEDEC[®] types
- Compression bonded encapsulations
- · Designed and qualified for industrial level
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- Converters
- Power supplies
- Machine tool controls
- High power drives
- Medium traction applications

MAJOR RATINGS AND CHARACTERISTICS					
PARAMETER	TEST CONDITIONS	VALUES	UNITS		
1		480	А		
I _{F(AV)}	T _C	120	°C		
I _{F(RMS)}		630			
I _{FSM}	50 Hz	8250	А		
	60 Hz	8640			
l ² t	50 Hz	340	kA ² s		
1-1	60 Hz	311	KA-S		
V _{RRM}	Range	1600 to 2400	V		
TJ		-40 to 190	°C		

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS							
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} MAXIMUM AT T _J = T _J MAXIMUM mA			
	16	1600	1700				
VS-SD400N/R	20	2000	2100	15			
	24	2400	2500				

Revision: 25-Nov-13

1

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FORWARD CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS
				400	A	
Maximum average forward current	I _{F(AV)}	100° and watter half size ways			120	°C A
at case temperature			180° conduction, half sine wave			
					100	°C
Maximum RMS forward current	I _{F(RMS)}	DC at 110	°C case tempe	rature	630	
		t = 10 ms	No voltage		8250	
Maximum peak, one-cycle forward,		t = 8.3 ms	reapplied	Sinusoidal half wave, initial T _J = T _J maximum	8640	A
non-repetitive surge current	I _{FSM}	t = 10 ms	100 % V _{RRM}		6940	
		t = 8.3 ms	reapplied		7270	
	l ² t	t = 10 ms	No voltage		340	- kA ² s
Movimum 12t for fueing		t = 8.3 ms	reapplied		311	
Maximum I ² t for fusing		t = 10 ms	100 % V _{RRM} reapplied		241	
		t = 8.3 ms			220	
Maximum I ² \sqrt{t} for fusing	l²√t	t = 0.1 to 1	0 ms, no voltaç	ge reapplied	3400	kA²√s
Low level value of threshold voltage	V _{F(TO)1}	(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum			0.80	v
High level value of threshold voltage	V _{F(TO)2}	$(I > \pi x I_{F(AV)}), T_J = T_J maximum$			0.85	
Low level value of forward slope resistance	r _{f1}	(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum			0.55	- mW
High level value of forward slope resistance	r _{f2}	$(I > \pi x I_{F(AV)}), T_J = T_J maximum$			0.51	11100
Maximum forward voltage drop	V _{FM}		A, T _J = T _J maxi sinusoidal wav		1.62	V

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	SYMBOL TEST CONDITIONS		UNITS	
Maximum junction operating temperature range	TJ	-40 to		°C	
Maximum storage temperature range	T _{Stg}		-55 to 200		
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	0.11	0.11 0.04	
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased	0.04		
Maximum allowed mounting torque ± 10 %		Not-lubricated threads	27	Nm	
Approximate weight			250	g	
Case style		See dimensions (link at the end of datasheet) DO-205AB (DO-9)			

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$\Delta \mathbf{R}_{\text{thJC}}$ CONDUCTION				
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS
180°	0.020	0.013		
120°	0.023	0.023		
90°	0.029	0.031	$T_J = T_J$ maximum	K/W
60°	0.042	0.044		
30°	0.073	0.074		

Note

• The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

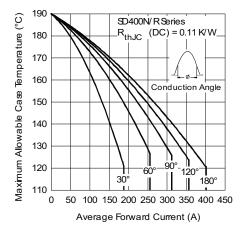
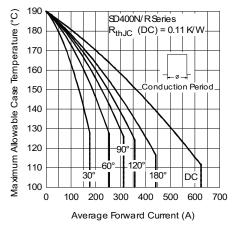


Fig. 1 - Current Ratings Characteristics





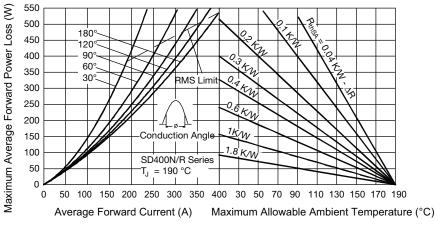
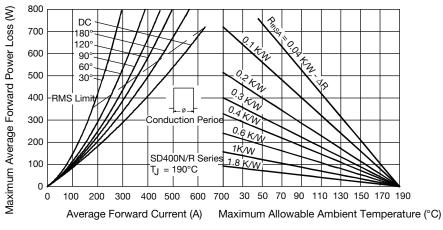


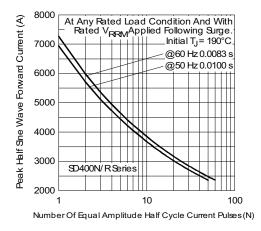
Fig. 3 - Forward Power Loss Characteristics

VS-SD400N/R Series

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Fig. 5 - Maximum Non-Repetitive Surge Current

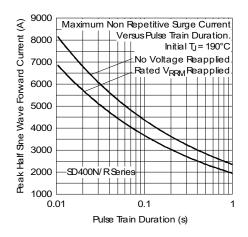


Fig. 6 - Maximum Non-Repetitive Surge Current

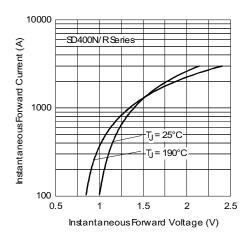


Fig. 7 - Forward Voltage Drop Characteristics

VS-SD400N/R Series

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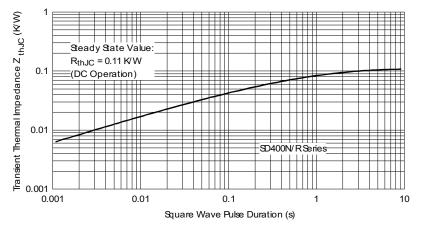


Fig. 8 - Thermal Impedance Z_{thJC} Characteristic

ORDERING INFORMATION TABLE

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Device code	vs-	SD	40	0	N	24	Ρ	С
	1	2	3	4	5	6	7	8
	1 - 2 -	Vishay Diode	Semico	onductor	s produ	ct		
	3 -	- Essential part number						
	4 -	0 = Standard recovery						
	5 -	 N = Stud normal polarity (cathode to stud) 						
		• R = 8	Stud rev	erse pol	arity (ar	node to :	stud)	
	6 -	Voltage	e code x	(100 = \	/ _{RRM} (s	ee Volta	ige Rati	ngs table
	7 -	P = Stu	ud base	DO-205	5AB (DC	0-9) 3/4"	16UNF	-2A
	8 -	C = Ce	eramic h	ousing				

For metric device M16 x 1.5 contact factory

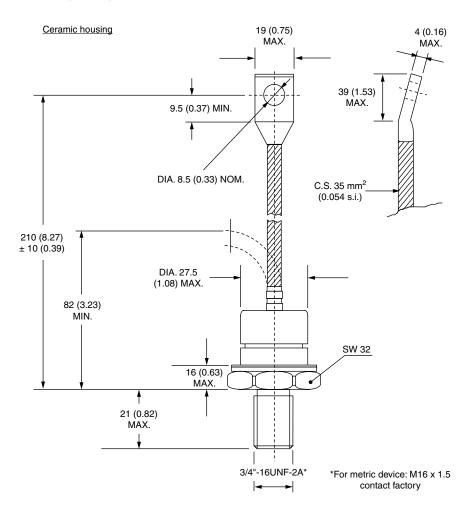
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95301			

Vishay Semiconductors



DO-205AB (DO-9)

DIMENSIONS in millimeters (inches)





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